

SN74CBTLV3257-Q1 Low-Voltage 4-Bit 1-of-2 FET Multiplexer/Demultiplexer

1 Features

- 5Ω Switch Connection Between Two Ports
- Rail-to-Rail Switching on Data I/O Ports
- I_{off} Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000V Human-Body Model (A114-A)
 - 200V Machine Model (A115-A)

2 Applications

- Analog and digital multiplexing and demultiplexing
- Diagnostics and monitoring
- [Zonal Architecture](#)
- [Body control modules](#)
- [Battery management systems \(BMS\)](#)
- [HVAC control module](#)
- ADAS
- [On-board \(OBC\) and wireless charging](#)
- [Automotive head unit](#)
- [Telematics](#)

3 Description

The SN74CBTLV3257-Q1 device is a 4-bit 1-of-2 highspeed FET multiplexer/demultiplexer. The low onstate resistance of the switch allows connections to be made with minimal propagation delay.

The select (S) input controls the data flow. The FET multiplexers/demultiplexers are disabled when the output-enable ($\overline{OE}$) input is high.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

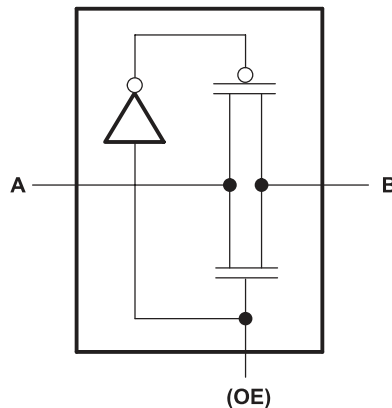
To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾
SN74CBTLV3257-Q1	DYY (SOT, 16)	4.2mm × 2.0mm
	PW (TSSOP, 16)	5.0mm × 4.4mm
	BQB (TSSOP, 16)	3.5mm × 2.5mm

(1) For more information, see [Section 11](#).

(2) The package size (length × width) is a nominal value and includes pins, where applicable.



Simplified Schematic (Each FET Switch)



Table of Contents

1 Features	1	7.4 Device Functional Modes.....	9
2 Applications	1	8 Application and Implementation	10
3 Description	1	8.1 Application Information.....	10
4 Pin Configuration and Functions	3	8.2 Typical Application.....	10
4.1 Pin Configuration and Functions.....	3	8.3 Power Supply Recommendations.....	11
5 Specifications	5	8.4 Layout.....	11
5.1 Absolute Maximum Ratings.....	5	9 Device and Documentation Support	13
5.2 ESD Ratings.....	5	9.1 Documentation Support.....	13
5.3 Recommended Operating Conditions.....	5	9.2 Receiving Notification of Documentation Updates....	13
5.4 Thermal Information.....	5	9.3 Support Resources.....	13
5.5 Electrical Characteristics.....	6	9.4 Trademarks.....	13
5.6 Switching Characteristics.....	6	9.5 Electrostatic Discharge Caution.....	13
5.7 Typical Characteristics.....	7	9.6 Glossary.....	13
6 Parameter Measurement Information	8	10 Revision History	13
7 Detailed Description	9	11 Mechanical, Packaging, and Orderable Information	13
7.1 Overview.....	9	11.1 Mechanical Data.....	14
7.2 Functional Block Diagram.....	9		
7.3 Feature Description.....	9		

4 Pin Configuration and Functions

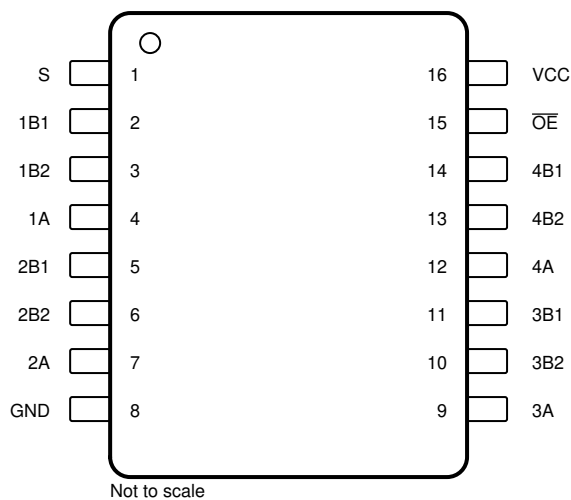


Figure 4-1. DYY, and PW Package 16-Pin SOT-23-THIN, and TSSOP (Top View)

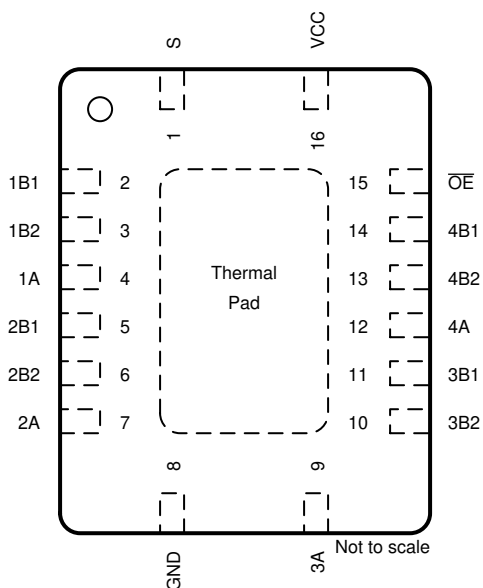


Figure 4-2. BQB Package 16-Pin WQFN (Top View)

4.1 Pin Configuration and Functions

Table 4-1. Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
S	1	I/O	Select
1B1	2	I/O	Channel 1 in/out 1
1B2	3	I/O	Channel 1 in/out 2
1A	4	I/O	Channel 1 out/in common
2B1	5	I/O	Channel 2 in/out 1
2B2	6	I/O	Channel 2 in/out 2
2A	7	I/O	Channel 2 out/in common
GND	8	—	Ground
3A	9	I/O	Channel 3 out/in common
3B2	10	I/O	Channel 3 in/out 2
3B1	11	I/O	Channel 3 in/out 1
4A	12	I/O	Channel 4 out/in common
4B2	13	I/O	Channel 4 in/out 2
4B1	14	I	Channel 4 in/out 1
$\overline{OE}$	15	I/O	Output Enable, active low
V _{CC}	16	—	Power

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
V _{CC}	Supply voltage	−0.5	4.6	V
V _I	Input voltage ⁽²⁾	−0.5	4.6	V
	Continuous channel current		128	mA
I _{IK}	Input clamp current	V _{I/O} < 0	−50	mA
T _J	Junction temperature		150	°C
T _{stg}	Storage temperature	−65	150	°C

- (1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. *Absolute Maximum Ratings* do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If used outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

5.2 ESD Ratings

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	2000	V

- (1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
V _{CC}	Supply voltage	2.3	3.6	V
V _{IH}	High-level control input voltage	V _{CC} = 2.3V to 2.7V V _{CC} = 2.7V to 3.6V	1.7 2	V
V _{IL}	Low-level control input voltage	V _{CC} = 2.3V to 2.7V V _{CC} = 2.7V to 3.6V	0.7 0.8	V
T _A	Operating free-air temperature	−40	125	°C

- (1) All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See [Implications of Slow or Floating CMOS Inputs](#).

5.4 Thermal Information

THERMAL METRIC ⁽¹⁾		SN74CBTLV3257-Q1			UNIT
		PW (TSSOP)	BQB (WQFN)	DYY (SOT)	
		16 PINS	16 PINS	16 Pins	
R _{θJA}	Junction-to-ambient thermal resistance	129.1	88.11	129.9	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	67.0	58.34	78.4	°C/W
R _{θJB}	Junction-to-board thermal resistance	87.1	17.01	73.3	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	14.5	58.27	17.2	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	86.3	85.06	72.4	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	37.54	N/A	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC package thermal metrics](#) application report.

5.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT
V_{IK}		$V_{CC} = 3V$,	$I_I = -18mA$			-1.2	V
I_I		$V_{CC} = 3.6V$,	$V_I = V_{CC}$ or GND			± 1	μA
I_{off}		$V_{CC} = 0$,	V_I or $V_O = 0$ to 3.6V			15	μA
I_{CC}		$V_{CC} = 3.6V$,	$I_O = 0$,			10	μA
ΔI_{CC} ⁽²⁾	Control inputs	$V_{CC} = 3.6V$,	One input at 3V,			300	μA
C_i		$V_I = 3V$ or 0	Other inputs at V_{CC} or GND		3		pF
$C_{io(OFF)}$	A port	$V_O = 3V$ or 0,	$\overline{OE} = V_{CC}$		10.5		pF
	B port				5.5		
r_{on} ⁽³⁾	$V_{CC} = 2.3V$, TYP at $V_{CC} = 2.5V$	$V_I = 0$	$I_I = 64mA$		5	8	Ω
			$I_I = 24mA$		5	8	
			$V_I = 1.7V$		27	40	
	$V_{CC} = 3V$	$V_I = 0$	$I_I = 64mA$		5	7	
			$I_I = 24mA$		5	7	
			$V_I = 2.4V$		10	15	

(1) All typical values are at $V_{CC} = 3.3V$ (unless otherwise noted), $T_A = 25^\circ C$.

(2) This is the increase in supply current for each input that is at the specified voltage level, rather than V_{CC} or GND.

(3) Measured by the voltage drop between the A and the B terminals at the indicated current through the switch. On-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

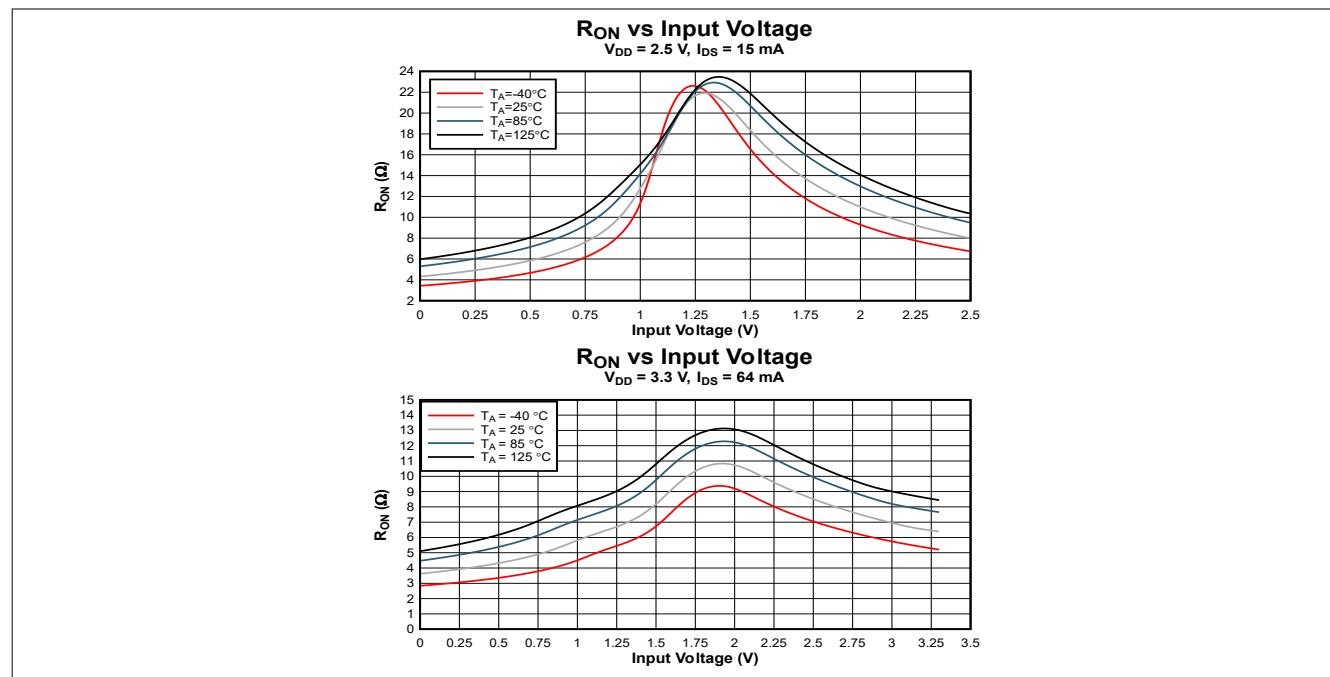
5.6 Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (See [Figure 6-1](#))

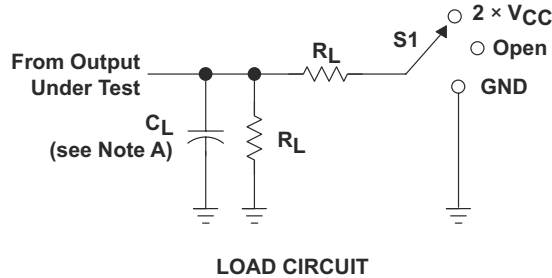
PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 2.5 \pm 0.2V$		$V_{CC} = 3.3V \pm 0.3V$		UNIT
			MIN	MAX	MIN	MAX	
t_{pd}	A or B ⁽¹⁾	B or A		0.15		0.25	ns
	S	A or B	1.8	6.1	1.8	5.3	
t_{en}	S	A or B	1.7	6.1	1.7	5.3	ns
t_{dis}	S	A or B	1	4.8	1	4.5	ns
t_{en}	$\overline{OE}$	A or B	1.9	5.6	2	5	ns
t_{dis}	$\overline{OE}$	A or B	1	5.5	1.6	5.5	ns

(1) The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

5.7 Typical Characteristics

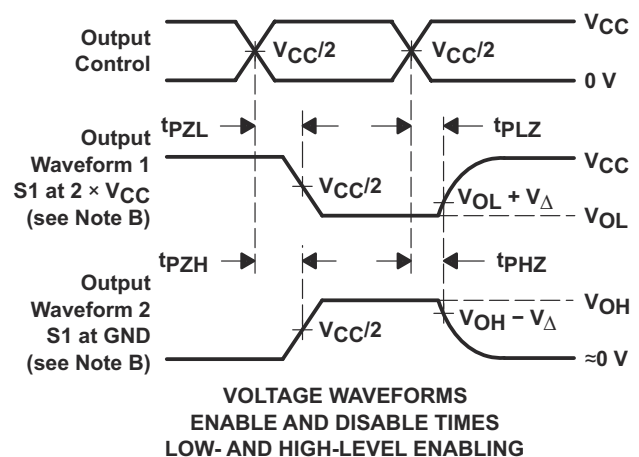
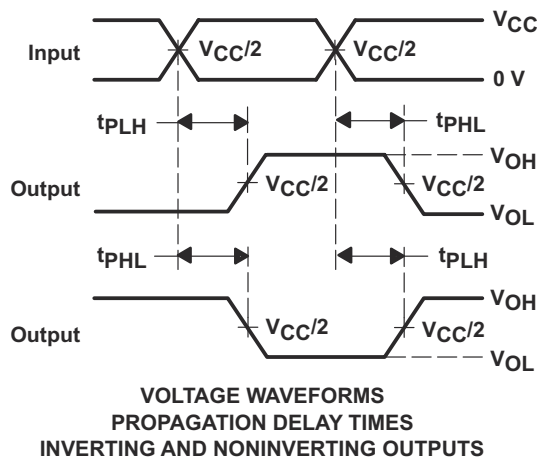
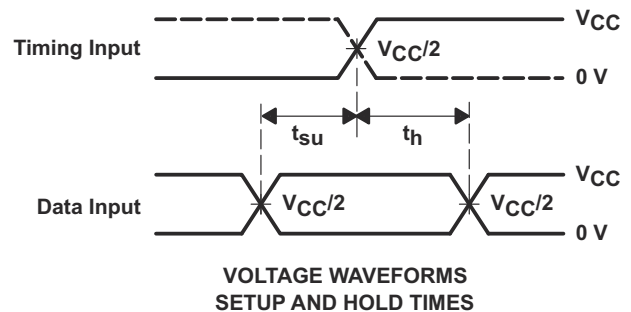
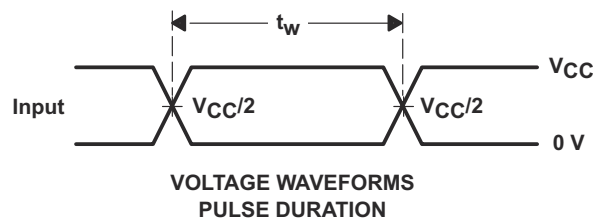


6 Parameter Measurement Information



TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	$2 \times V_{CC}$
t_{PHZ}/t_{PZH}	GND

V_{CC}	C_L	R_L	V_{Δ}
$2.5\text{ V} \pm 0.2\text{ V}$	30 pF	500 Ω	0.15 V
$3.3\text{ V} \pm 0.3\text{ V}$	50 pF	500 Ω	0.3 V



- NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10\text{ MHz}$, $Z_O = 50\ \Omega$, $t_r \leq 2\text{ ns}$, $t_f \leq 2\text{ ns}$.
D. The outputs are measured one at a time with one transition per measurement.
E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
F. t_{PZL} and t_{PZH} are the same as t_{en} .
G. t_{PLH} and t_{PHL} are the same as t_{pd} .
H. All parameters and waveforms are not applicable to all devices.

Figure 6-1. Load Circuit and Voltage Waveforms

7 Detailed Description

7.1 Overview

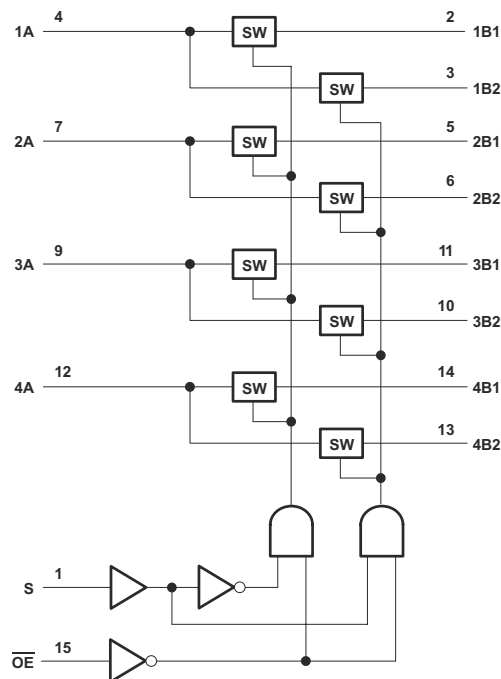
The SN74CBTLV3257-Q1 device is a 4-bit 1-of-2 high-speed FET multiplexer and demultiplexer. The low ON-state resistance of the switch allows connections to be made with minimal propagation delay.

The select (S) input controls the data flow. The FET multiplexers and demultiplexers are disabled when the output-enable ($\overline{OE}$) input is high.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

7.2 Functional Block Diagram



7.3 Feature Description

The SN74CBTLV3257-Q1 features 5Ω switch connection between ports, allowing for low signal loss across the switch. Rail-to-rail switching on data I/O allows for full voltage swing outputs. I_{off} supports partial-power-down mode operation, protecting the chip from voltages at output ports when it is not powered on. Latch-up performance exceeds 100mA per JESD 78, Class II.

7.4 Device Functional Modes

Table 7-1 shows the functional modes of SN74CBTLV3257-Q1.

Table 7-1. Function Table

INPUTS		FUNCTION
$\overline{OE}$	S	
L	L	A port = B1 port
L	H	A port = B2 port
H	X	Disconnect

8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The SN74CBTLV3257-Q1 can be used to multiplex and demultiplex up to 4 channels simultaneously in a 2:1 configuration. The application shown here is a 4-bit bus being multiplexed between two devices. the $\overline{OE}$ and S pins are used to control the chip from the bus controller. This is a very generic example, and could apply to many situations. If an application requires less than 4 bits, be sure to tie the A side to either high or low on unused channels.

8.2 Typical Application

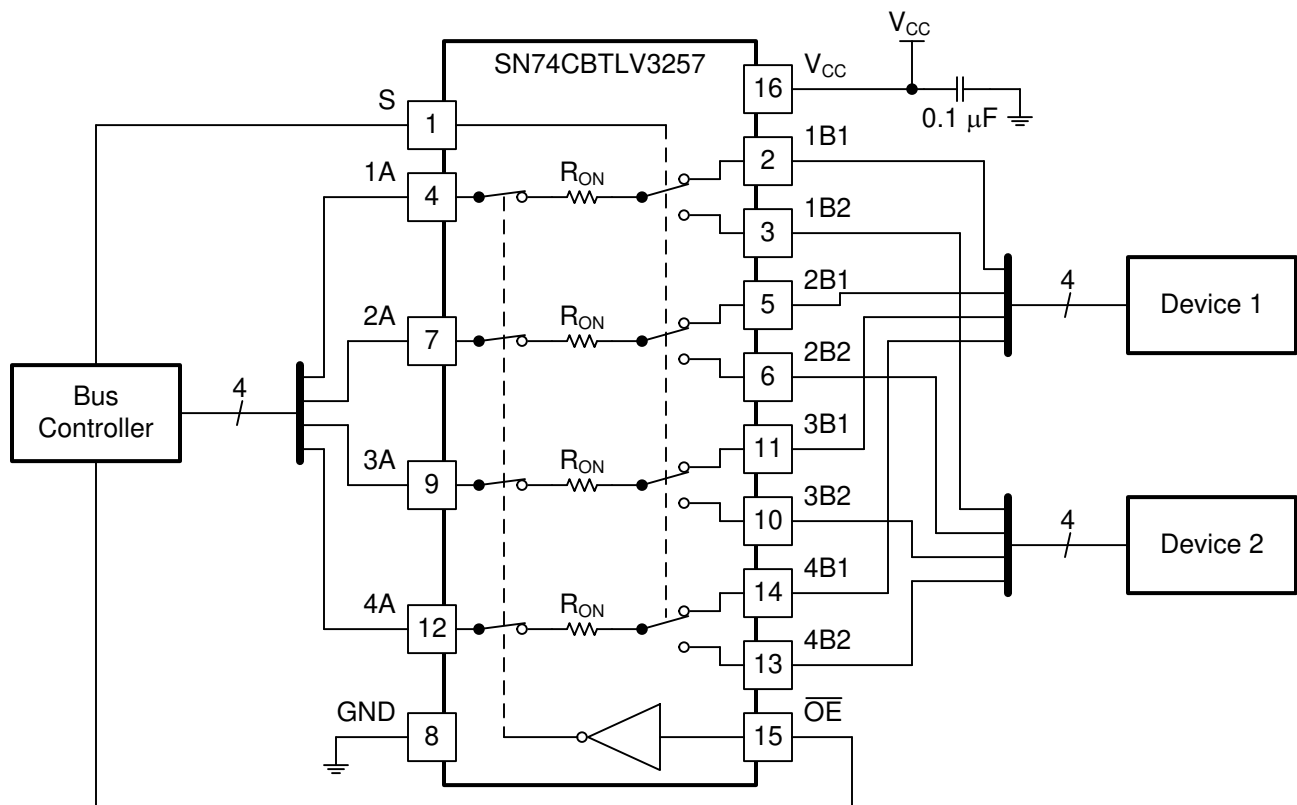


Figure 8-1. Typical Application of the SN74CBTLV3257-Q1

8.2.1 Design Requirements

- Recommended Input Conditions:
 - For specified high and low levels, see V_{IH} and V_{IL} in [Section 5.3](#).
 - Inputs and outputs are overvoltage tolerant slowing them to go as high as 4.6V at any valid V_{CC} .
- Recommended Output Conditions:
 - Load currents should not exceed $\pm 128\text{mA}$ per channel.
- Frequency Selection Criterion:
 - Maximum frequency tested is 200MHz.

- Added trace resistance/capacitance can reduce maximum frequency capability; use layout practices as directed in [Section 8.4](#).

8.2.2 Detailed Design Procedure

The 4-bit bus is connected directly to the 1A, 2A, 3A, and 4A ports (known as the xA port) on the SN74CBTLV3257-Q1, which essentially splits it into two busses, coming out of the xB1 and xB2 ports. When S is high, xB2 is the active bus, and when S is low, xB1 is the active bus. This means that Device 2 is connected to the bus controller when S is high, and Device 1 is connected to the bus controller when S is low. This setup is especially useful when two devices are hard coded with the same address and only one bus is available. The $\overline{OE}$ connection can be used to disconnect all devices from the bus controller if necessary.

The 0.1 μ F capacitor on V_{CC} is a decoupling capacitor and should be placed as close as possible to the device.

8.2.3 Application Curve

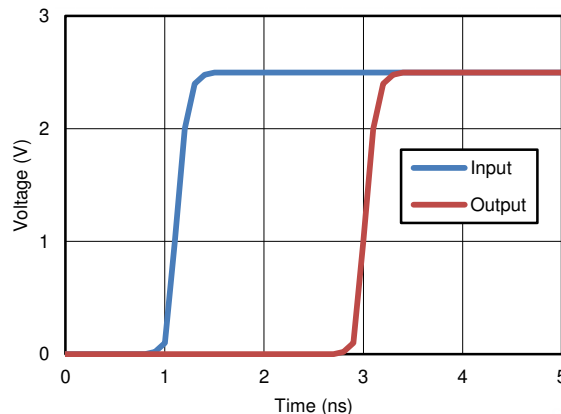


Figure 8-2. Propagation Delay (t_{pd}) Simulation Result at $V_{CC} = 2.5V$

8.3 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating listed in the [Section 5.3](#) table.

Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1 μ F bypass capacitor is recommended. If multiple pins are labeled V_{CC} , then a 0.01 μ F or 0.022 μ F capacitor is recommended for each V_{CC} because the V_{CC} pins are tied together internally. For devices with dual-supply pins operating at different voltages, for example V_{CC} and V_{DD} , a 0.1 μ F bypass capacitor is recommended for each supply pin. To reject different frequencies of noise, use multiple bypass capacitors in parallel. Capacitors with values of 0.1 μ F and 1 μ F are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

8.4 Layout

8.4.1 Layout Guidelines

Reflections and matching are closely related to the loop antenna theory but are different enough to be discussed separately from the theory. When a PCB trace turns a corner at a 90° angle, a reflection can occur. A reflection occurs primarily because of the change of width of the trace. At the apex of the turn, the trace width increases to 1.414 times the width. This increase upsets the transmission-line characteristics, especially the distributed capacitance and self-inductance of the trace which results in the reflection. Not all PCB traces can be straight and therefore some traces must turn corners. [Figure 8-3](#) shows progressively better techniques of rounding corners. Only the last example (BEST) maintains constant trace width and minimizes reflections.

8.4.2 Layout Example

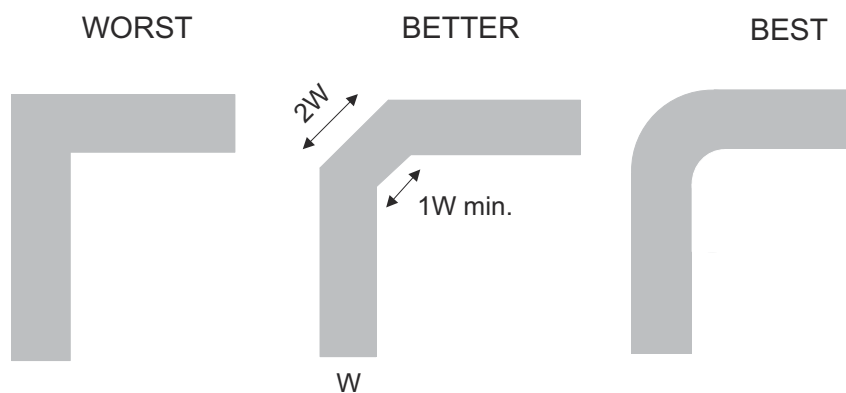


Figure 8-3. Trace Example

9 Device and Documentation Support

9.1 Documentation Support

9.1.1 Related Documentation

For related documentation see the following:

- Texas Instruments, [Implications of Slow or Floating CMOS Inputs application report](#)
- Texas Instruments, [Selecting the Right Texas Instruments Signal Switch application note](#)

9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](https://www.ti.com). Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

9.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.6 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

DATE	REVISION	NOTES
December 2025	*	Initial Release

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

11.1 Mechanical Data

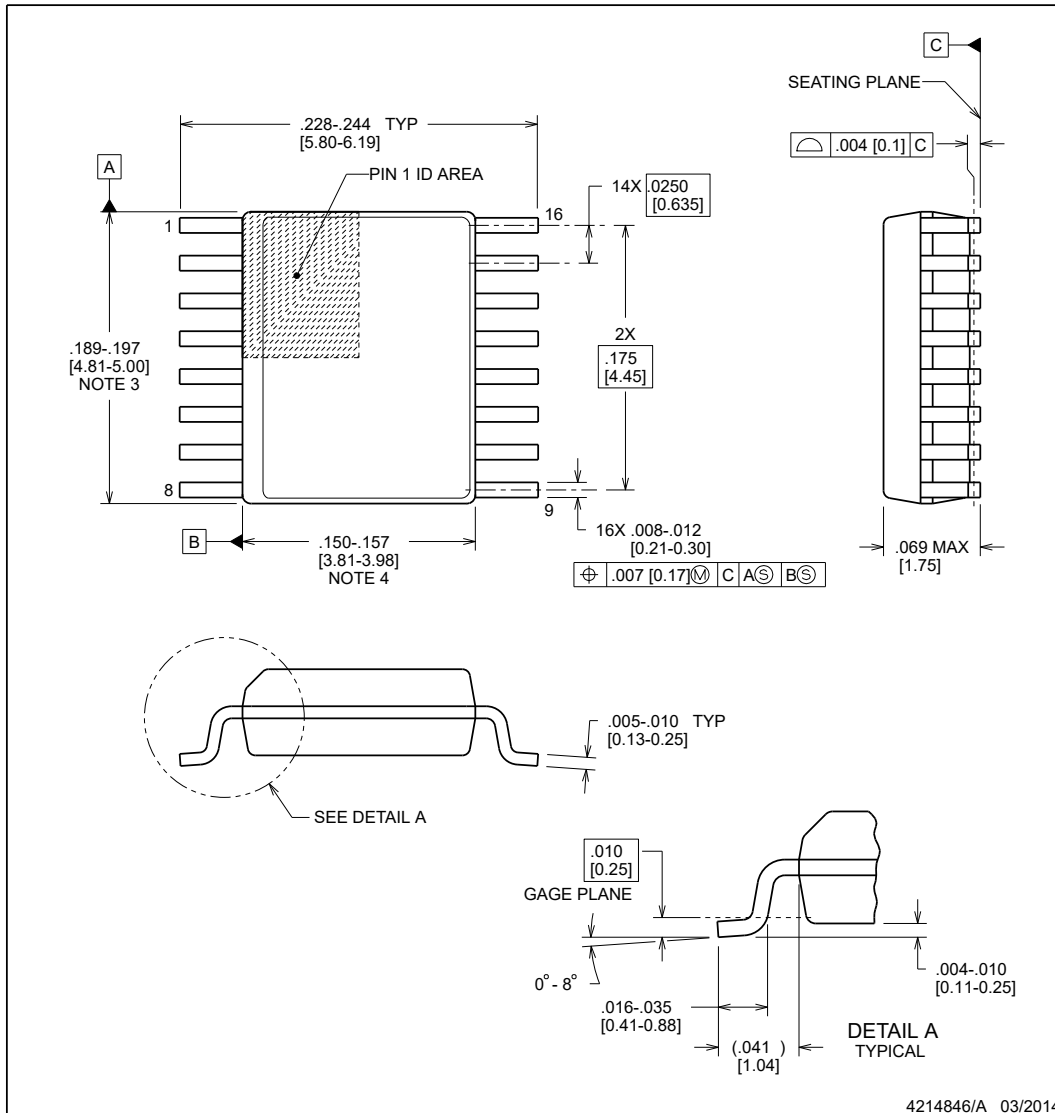


DBQ0016A

PACKAGE OUTLINE

SSOP - 1.75 mm max height

SHRINK SMALL-OUTLINE PACKAGE



NOTES:

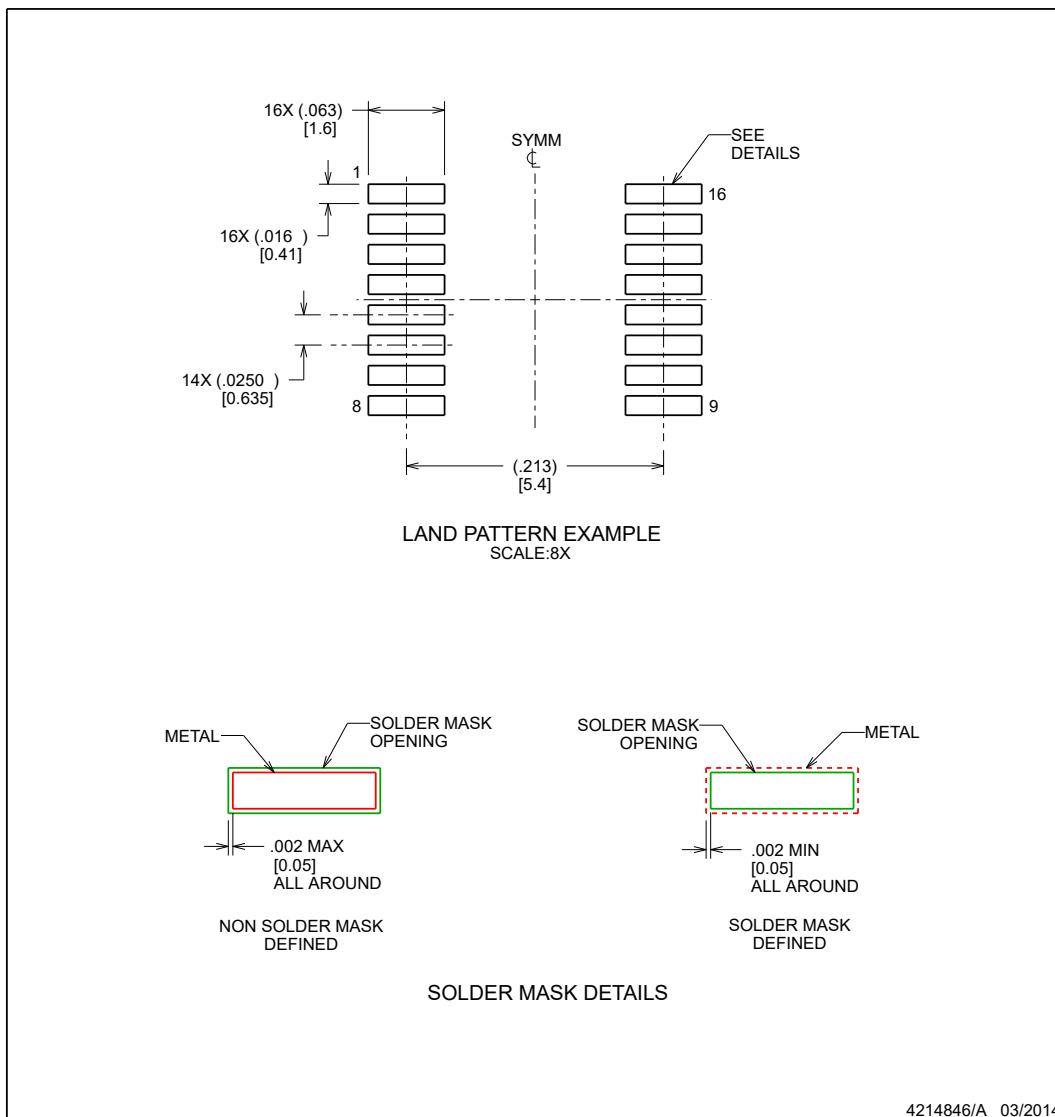
1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 inch, per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MO-137, variation AB.

EXAMPLE BOARD LAYOUT

DBQ0016A

SSOP - 1.75 mm max height

SHRINK SMALL-OUTLINE PACKAGE



NOTES: (continued)

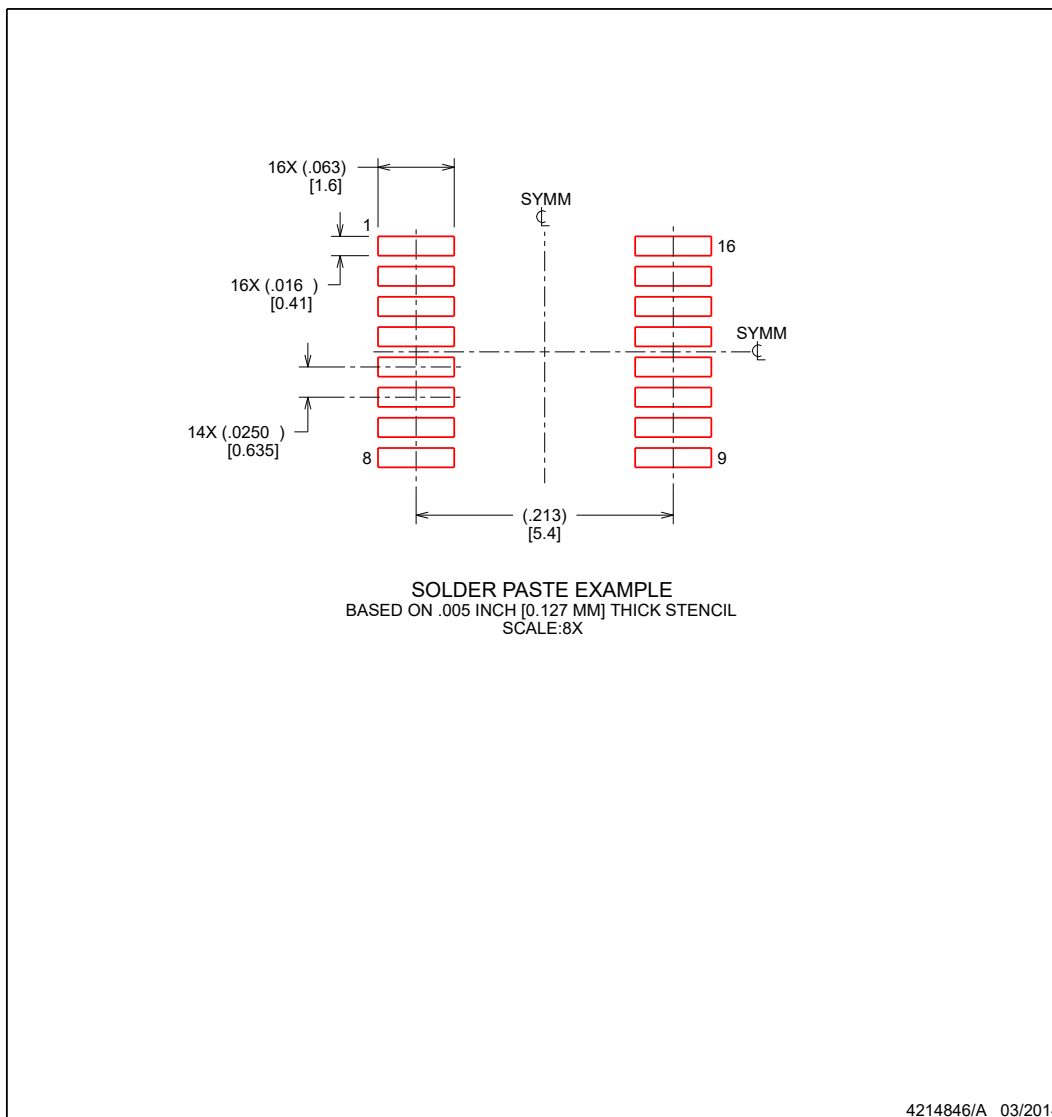
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBQ0016A

SSOP - 1.75 mm max height

SHRINK SMALL-OUTLINE PACKAGE



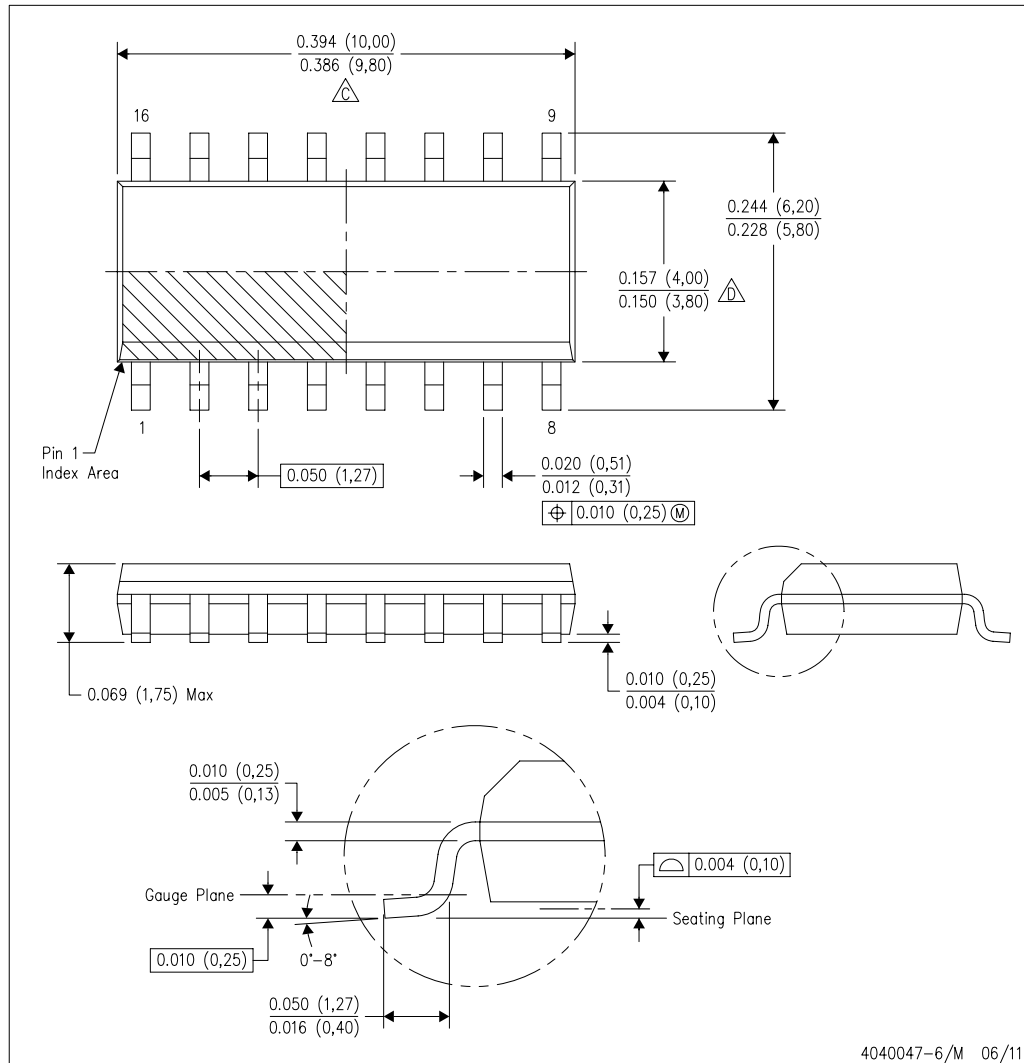
NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

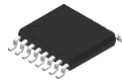
MECHANICAL DATA

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS-012 variation AC.

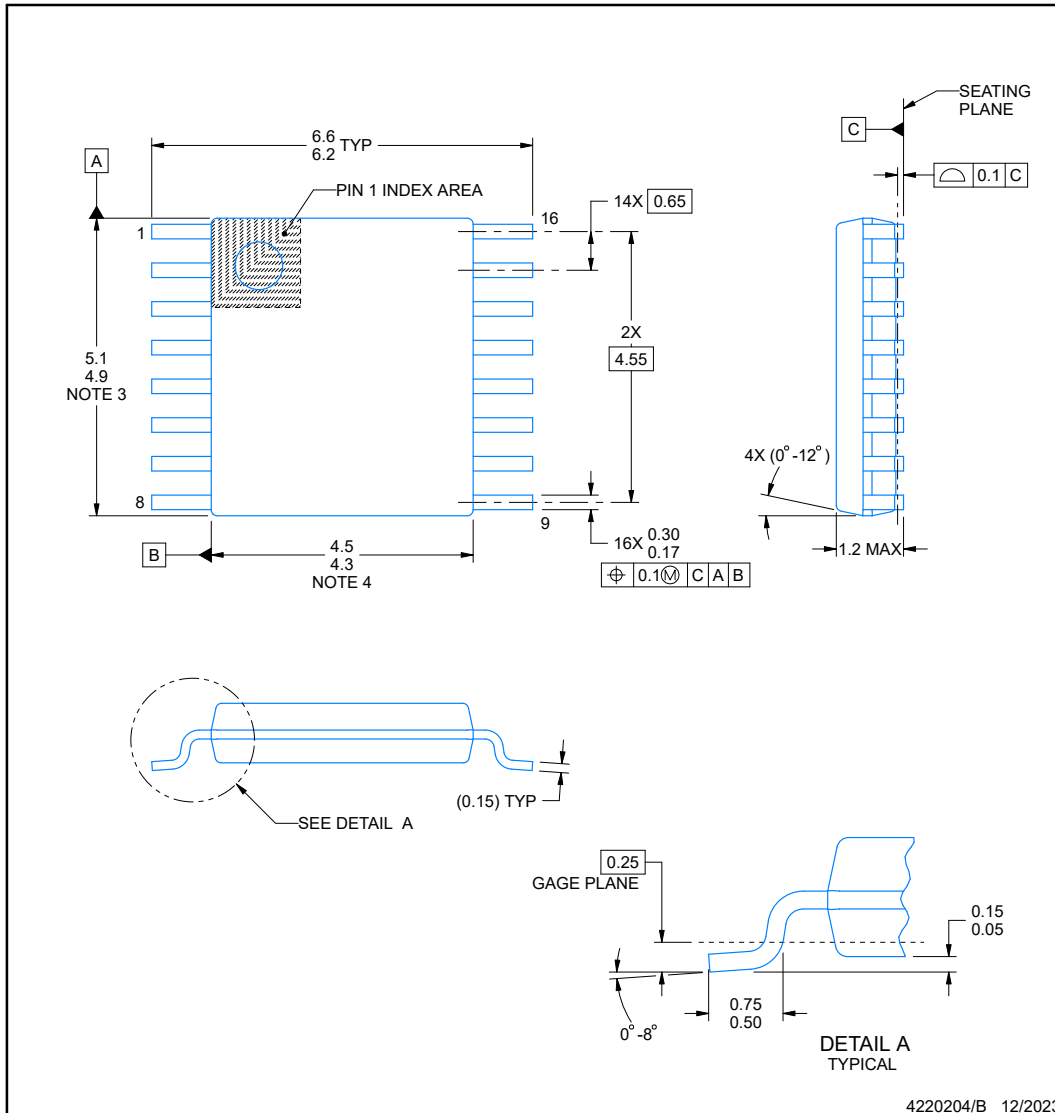


PW0016A

PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



TSSOP - 1.2 mm max height

Diagram illustrating a land pattern example with dimensions and symmetry:

- Overall width: 16X (1.5)
- Overall height: 16X (0.45)
- Internal height dimension: 14X (0.65)
- Number of rows: 8 (left), 9 (right)
- Radius: (R0.05) TYP
- Symmetry lines: SYMM (vertical and horizontal)
- Overall width dimension: (5.8)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X

NOTES: (continued)

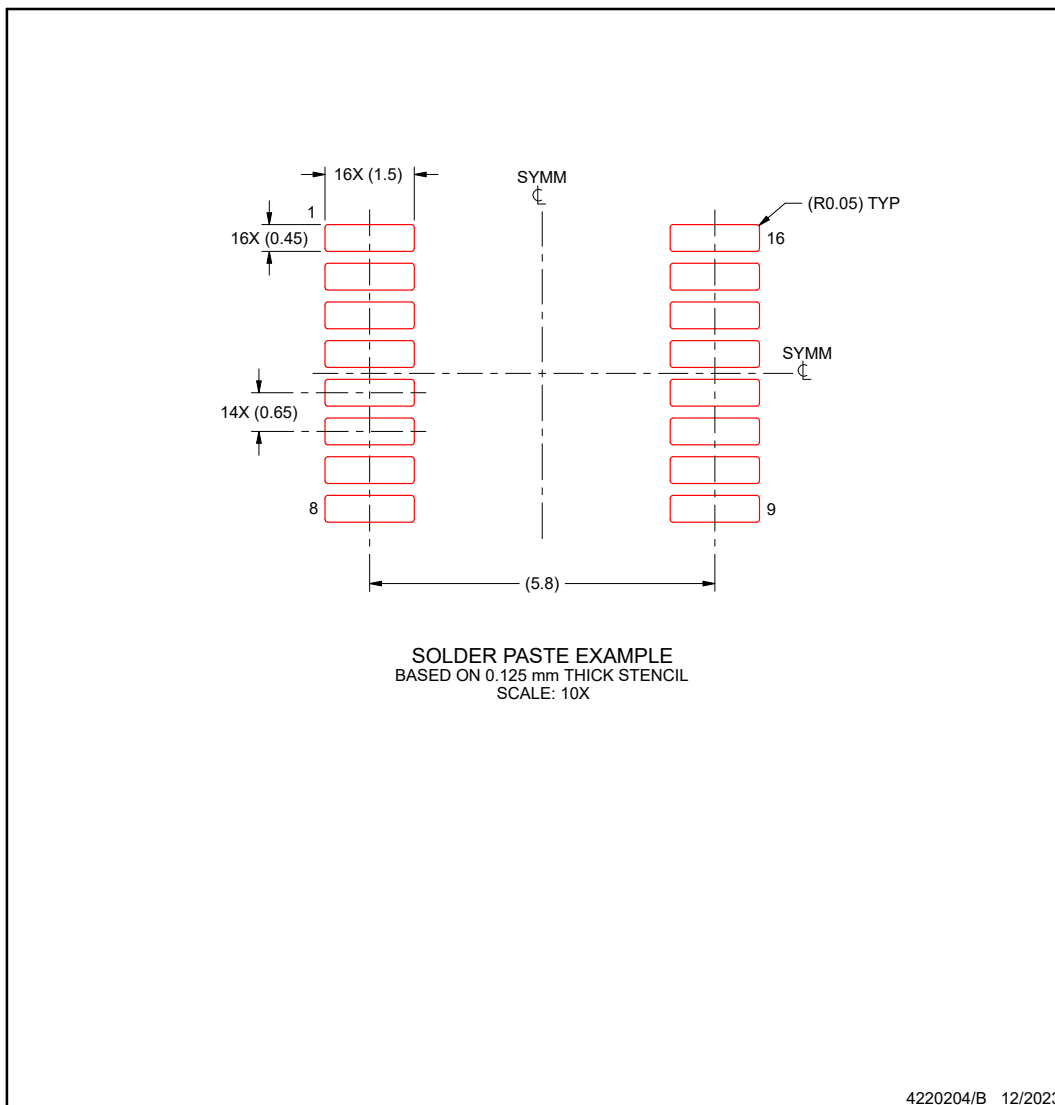
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EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE

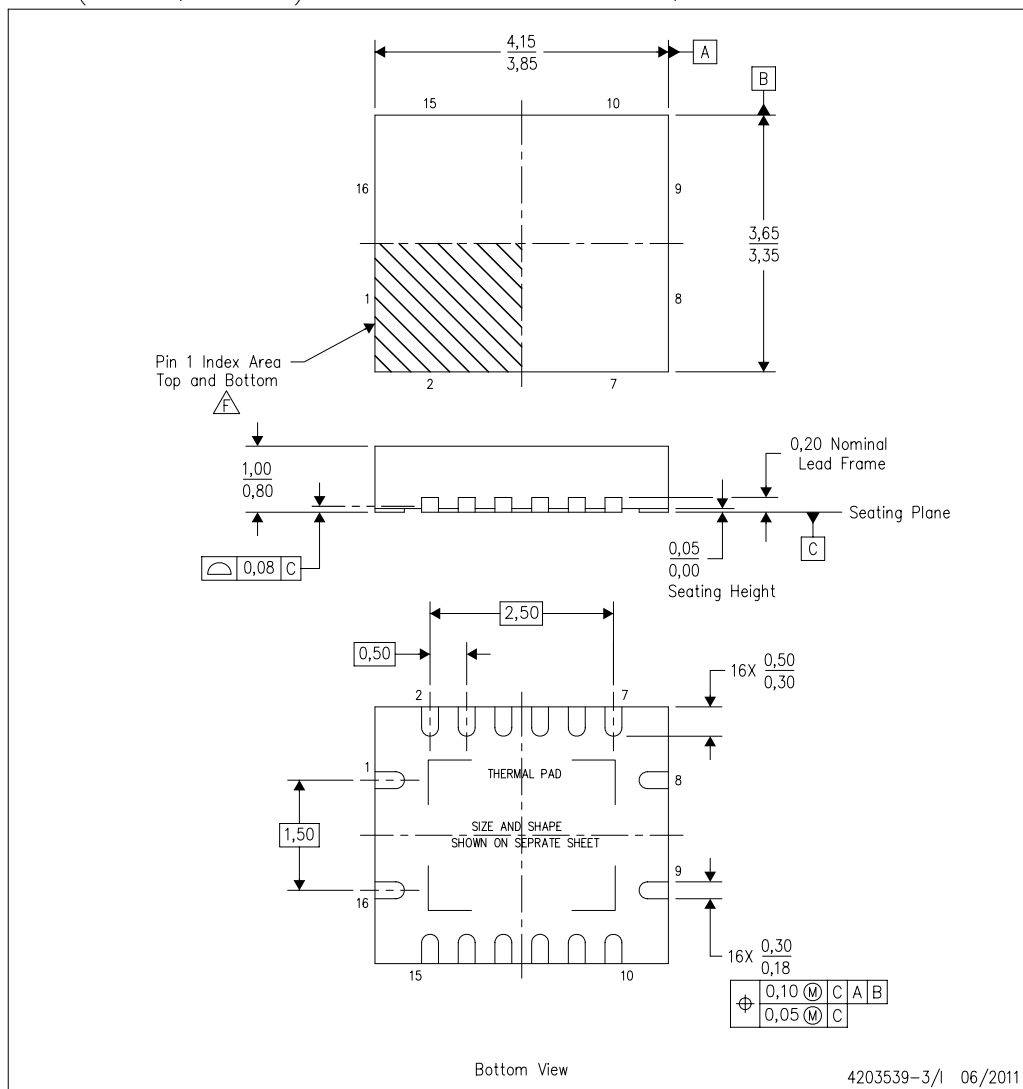


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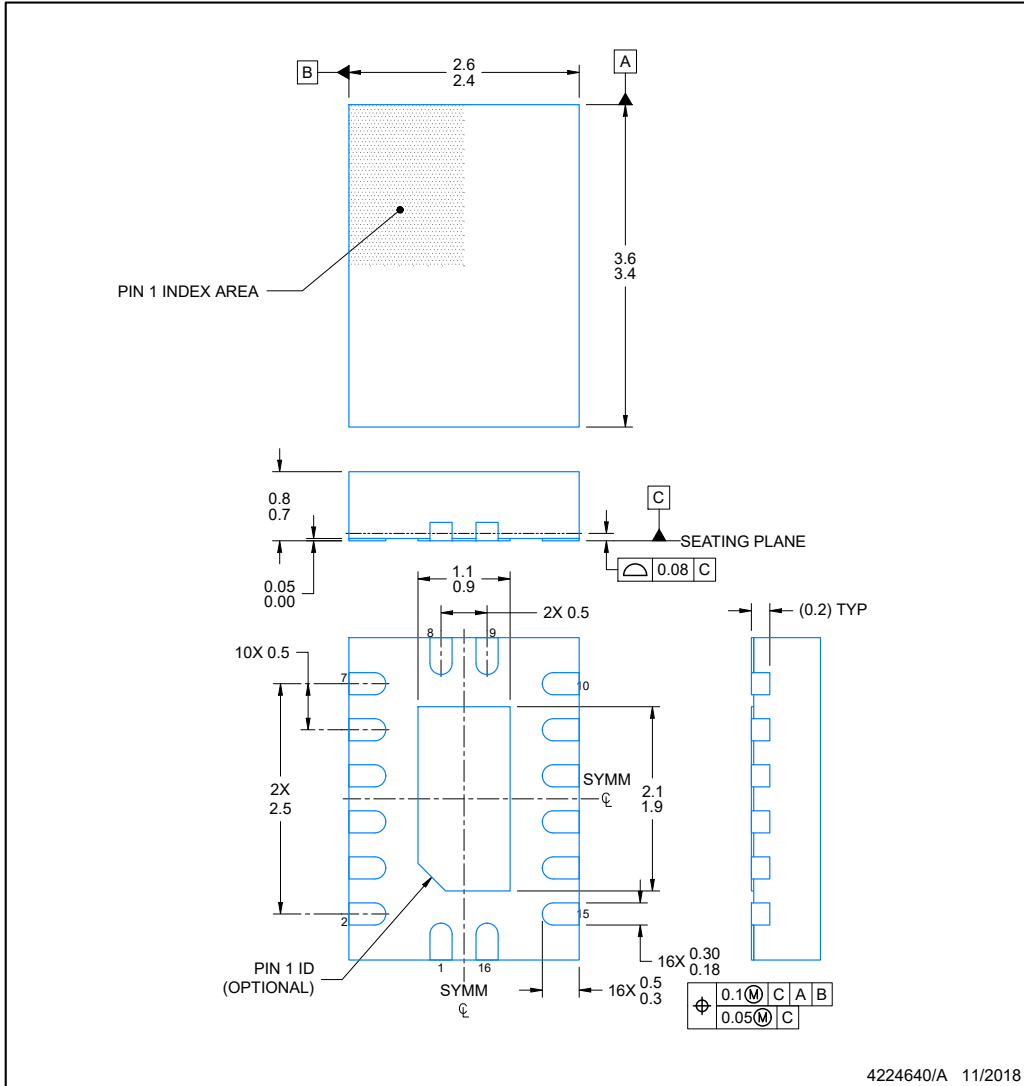
MECHANICAL DATA

RGY (R-PVQFN-N16) PLASTIC QUAD FLATPACK NO-LEAD



- NOTES:
- All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - This drawing is subject to change without notice.
 - QFN (Quad Flatpack No-Lead) package configuration.
 - The package thermal pad must be soldered to the board for thermal and mechanical performance.
 - See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
 - Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
 - Package complies to JEDEC MO-241 variation BA.

BQB0016A **PACKAGE OUTLINE**
WQFN - 0.8 mm max height
PLASTIC QUAD FLAT PACK-NO LEAD



NOTES:

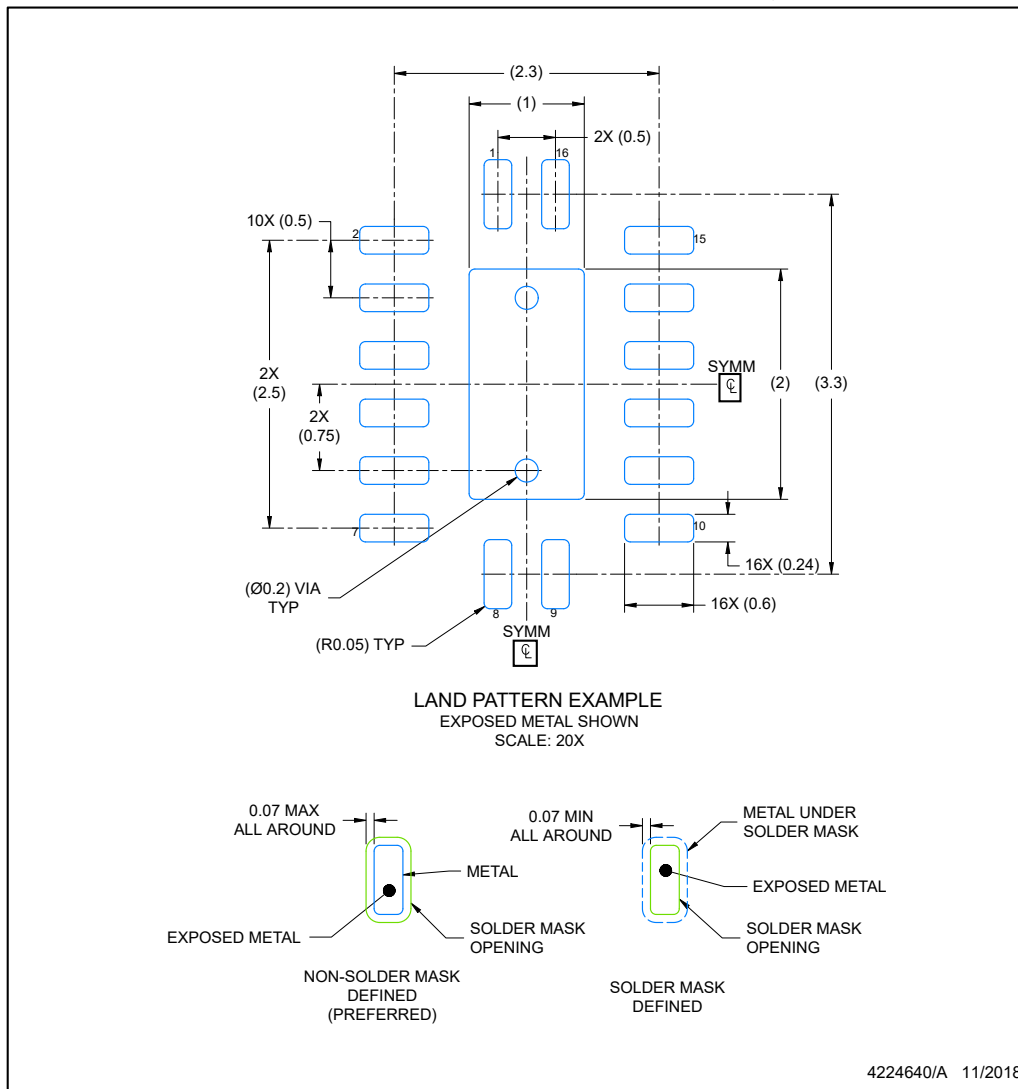
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

BQB0016A

WQFN - 0.8 mm max height

PLASTIC QUAD FLAT PACK-NO LEAD



NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

WQFN - 0.8 mm max height

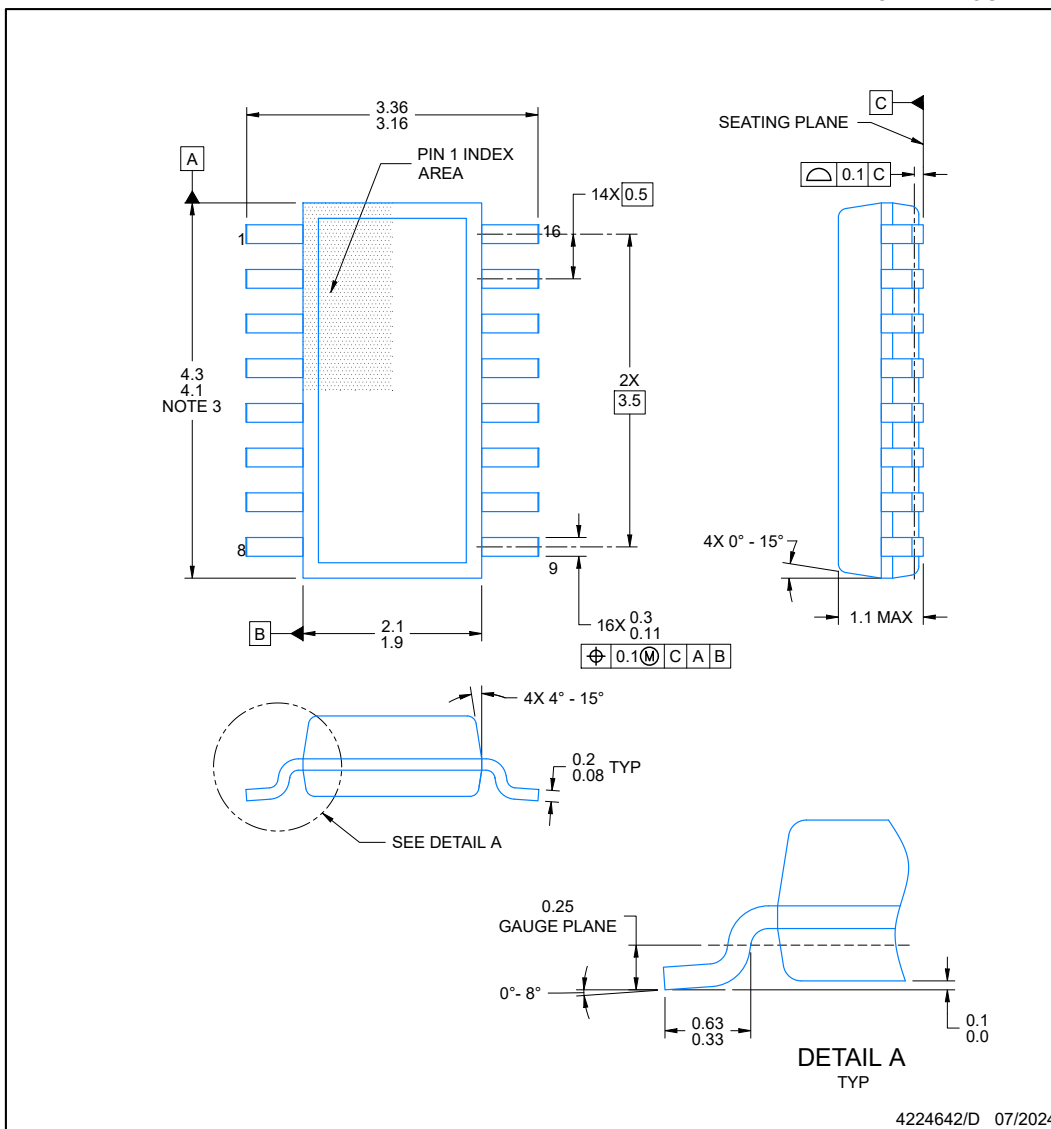
Technical drawing of a solder paste stencil layout. The drawing shows a central rectangular area with a blue border and a dashed red circle, surrounded by 16 numbered rectangular pads. Dimensions are given in inches and millimeters. Key dimensions include: overall width (2.3), overall height (3.3), pad width (0.95), pad height (0.5), and various offsets (10X 0.5, 2X 2.5, 16X 0.24, 16X 0.6). Symmetry is indicated by 'SYMM' and a center line. A note '(R0.05) TYP' points to a fillet. Labels 'EXPOSED METAL' and 'EXPOSED PAD' are present.

SOLDER PASTE EXAMPLE
 BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD
 85% PRINTED COVERAGE BY AREA
 SCALE: 20X

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

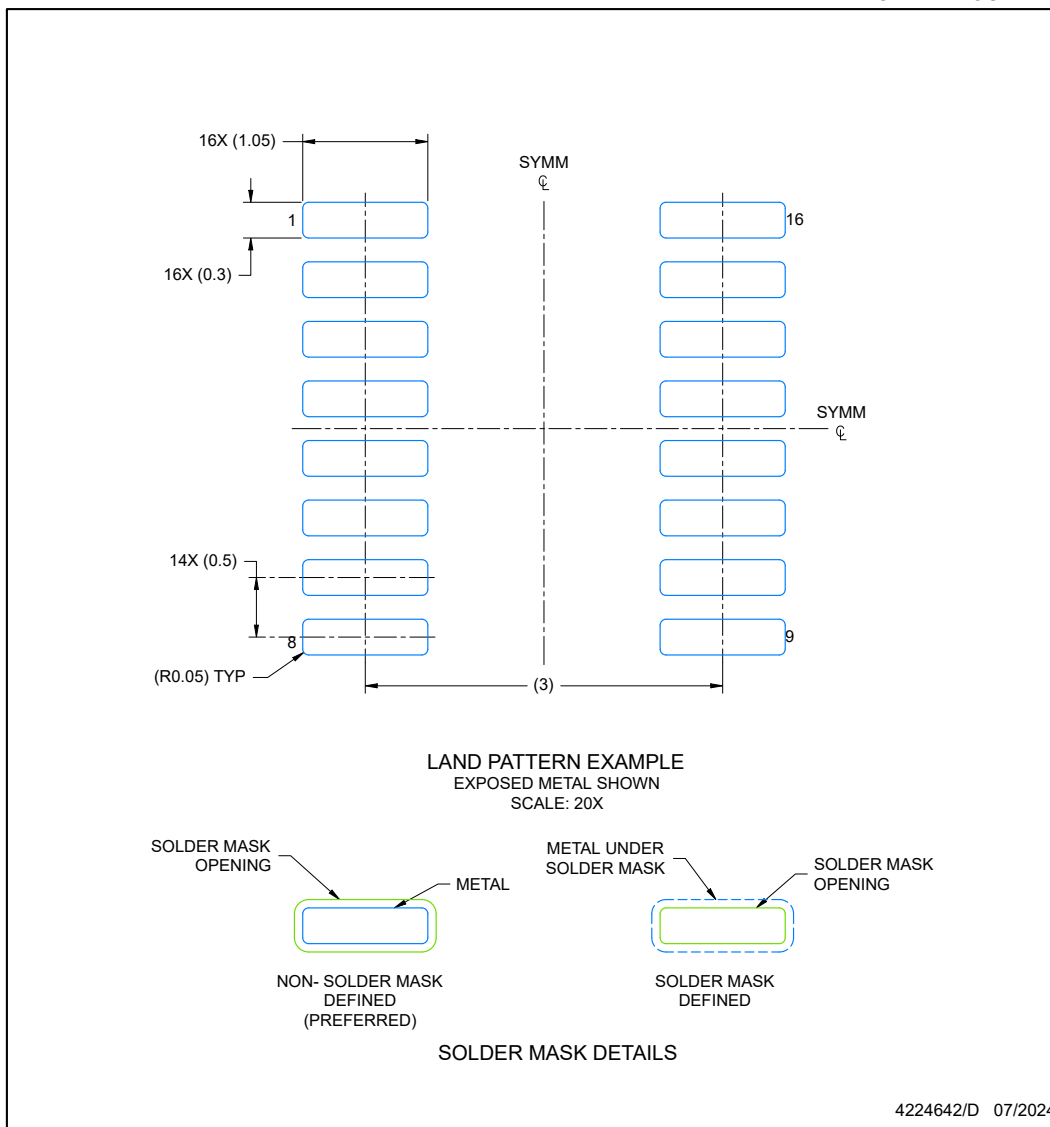
DYY0016A **PACKAGE OUTLINE**
SOT-23-THIN - 1.1 mm max height
PLASTIC SMALL OUTLINE



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
5. Reference JEDEC Registration MO-345, Variation AA

DYY0016A **EXAMPLE BOARD LAYOUT**
SOT-23-THIN - 1.1 mm max height
PLASTIC SMALL OUTLINE



NOTES: (continued)

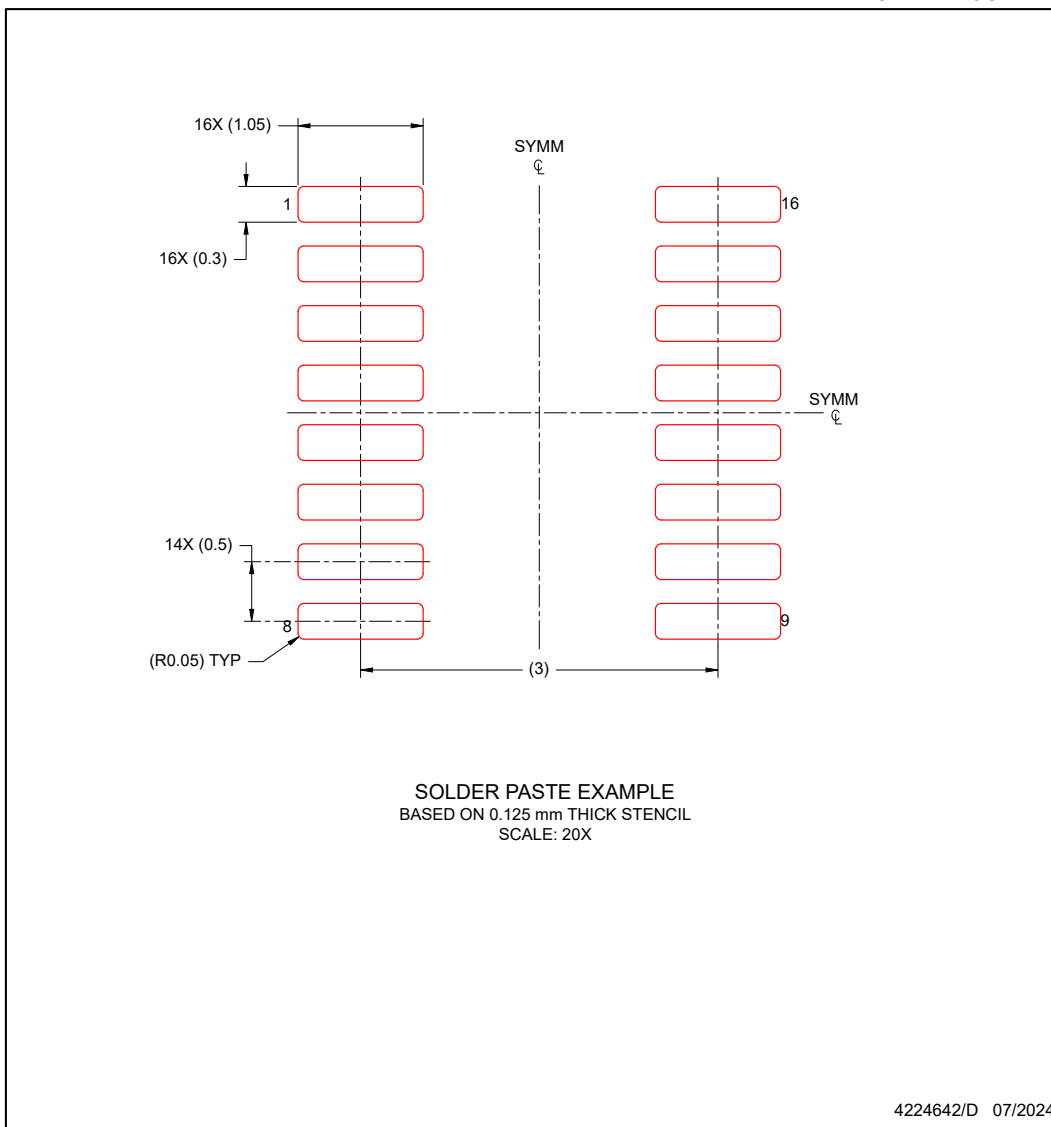
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

SOT-23-THIN - 1.1 mm max height

DYY0016A

PLASTIC SMALL OUTLINE



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
74CBTLV3257BQBRQ1	Active	Production	WQFN (BQB) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CL257Q
74CBTLV3257DYRQ1	Active	Production	SOT-23-THIN (DYY) 16	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	CL257Q
74CBTLV3257PWRQ1	Active	Production	TSSOP (PW) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CL257Q

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF SN74CBTLV3257-Q1 :

- Catalog : [SN74CBTLV3257](#)
- Enhanced Product : [SN74CBTLV3257-EP](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Enhanced Product - Supports Defense, Aerospace and Medical Applications

GENERIC PACKAGE VIEW

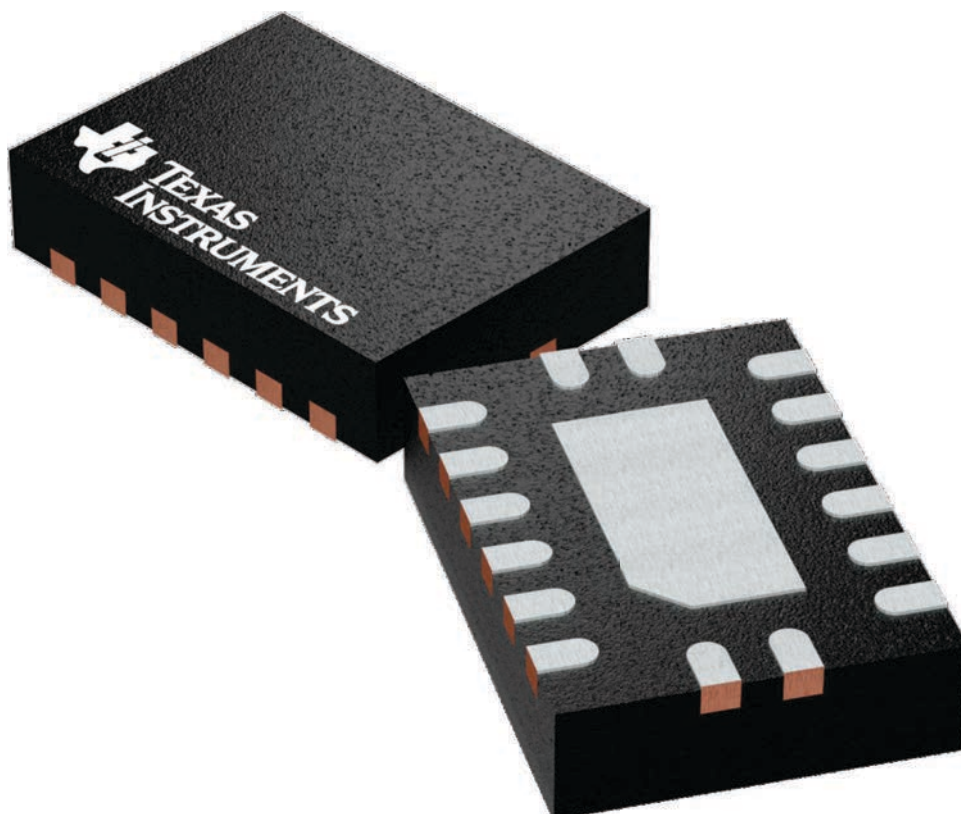
BQB 16

WQFN - 0.8 mm max height

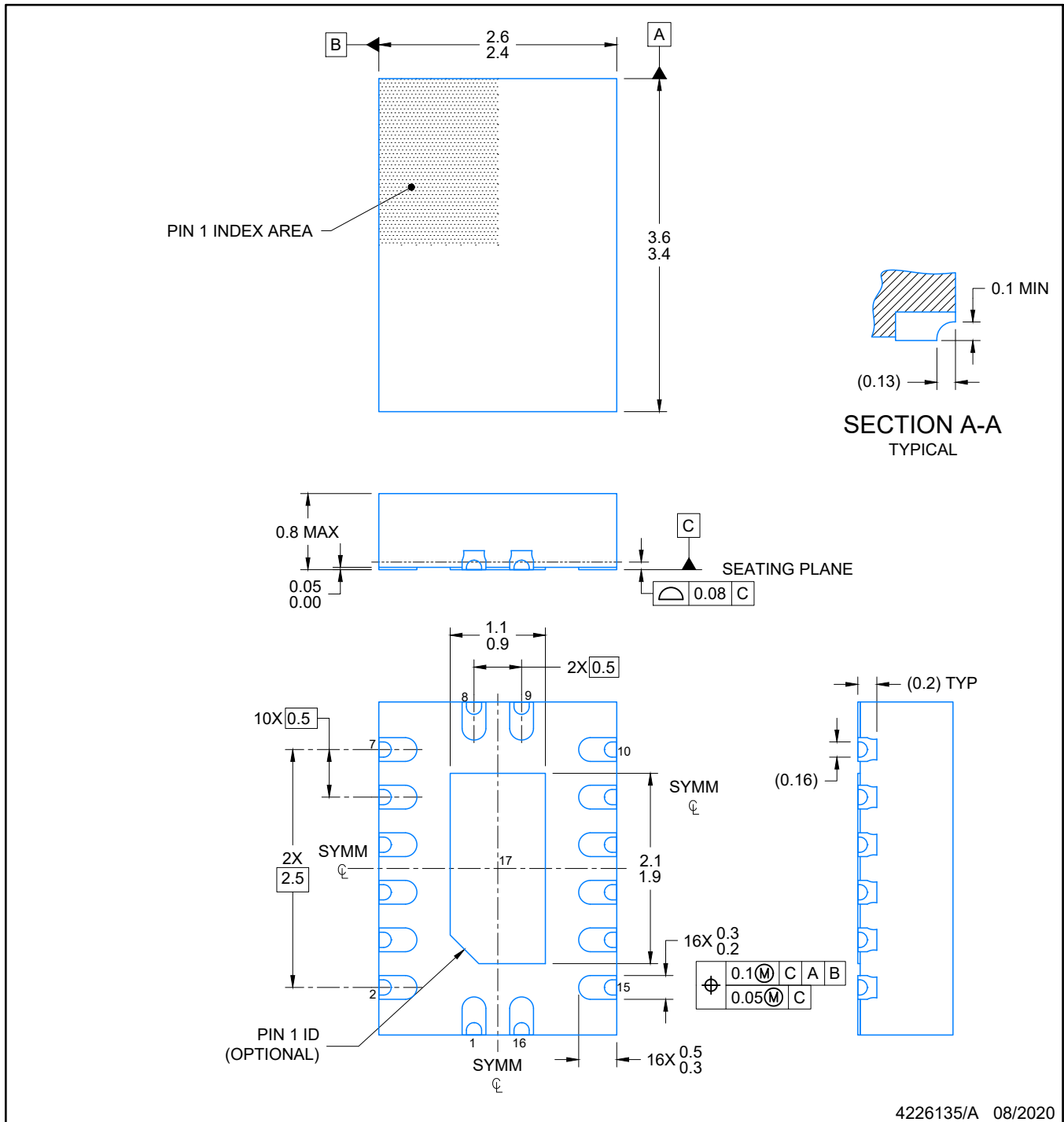
2.5 x 3.5, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

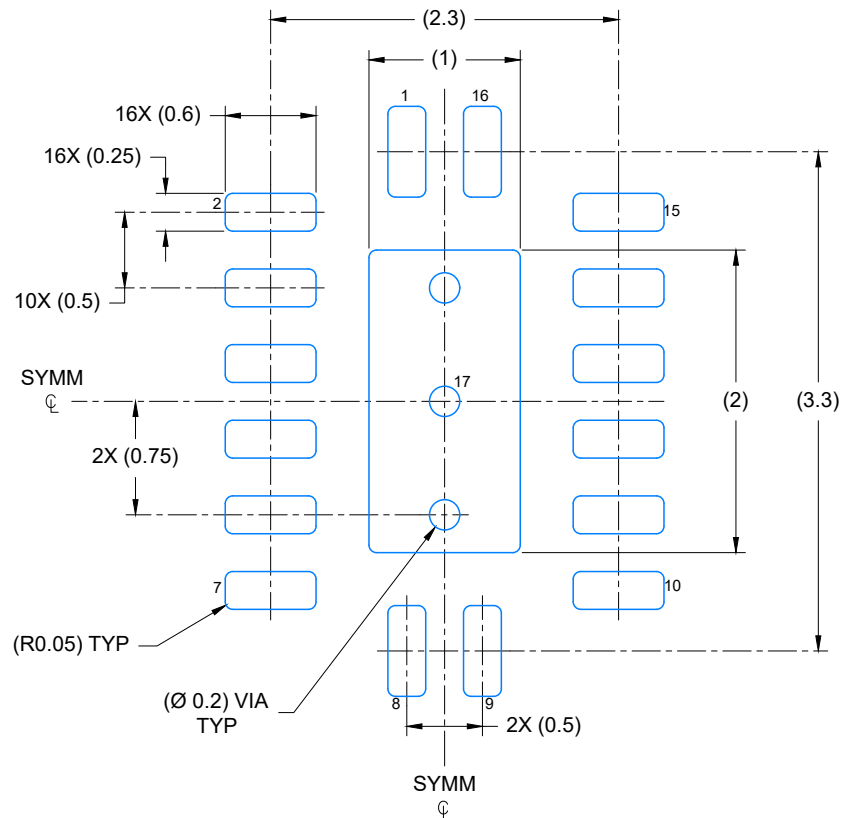


4226161/A



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.

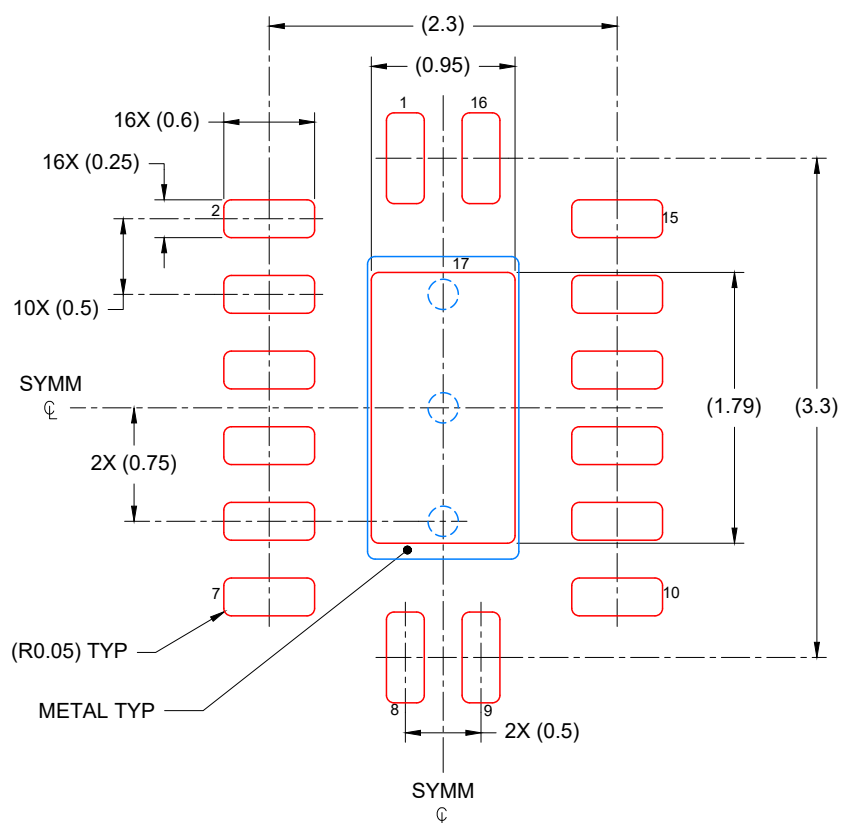


LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 20X

4226135/A 08/2020

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



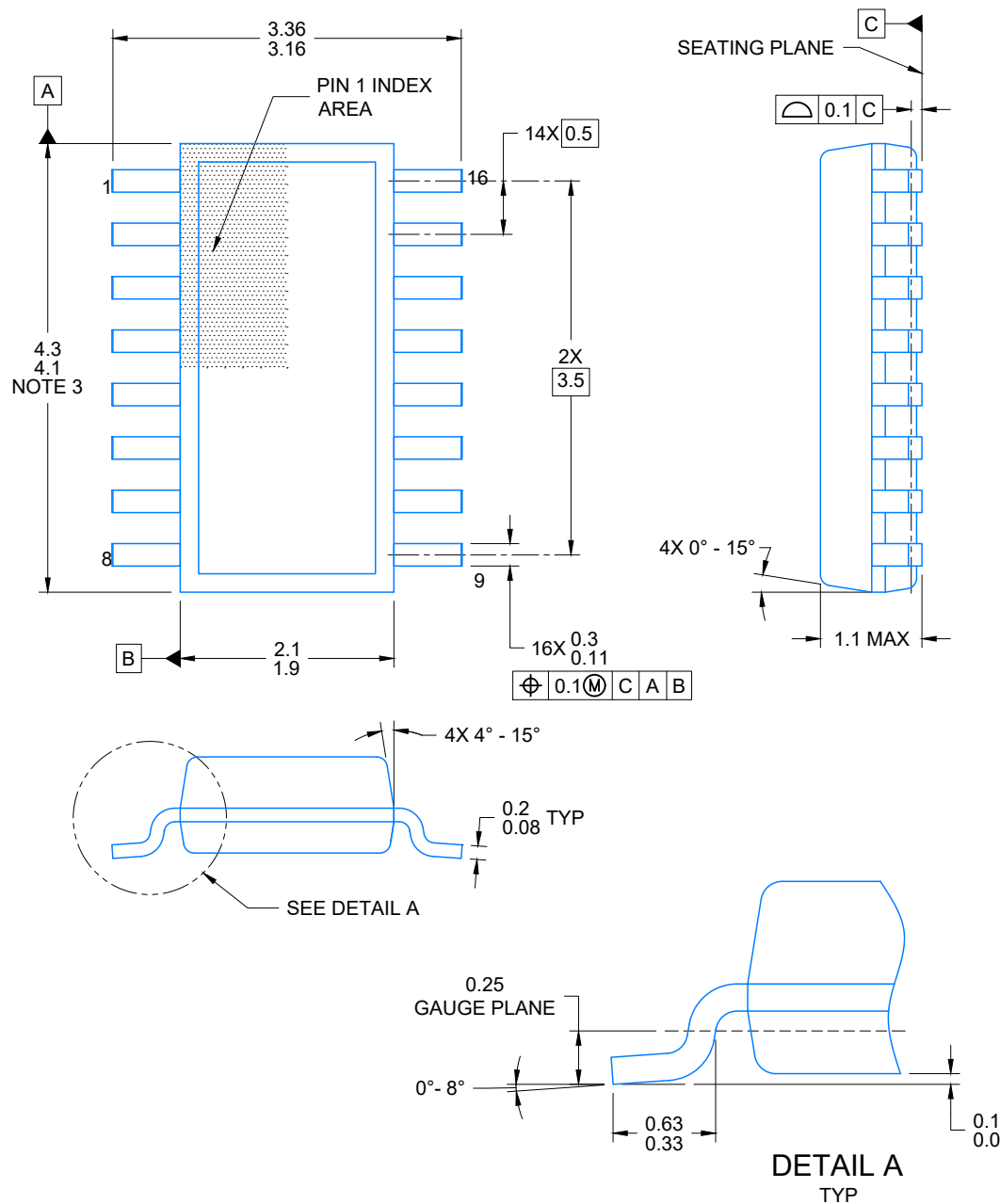
SOLDER PASTE EXAMPLE BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD
85% PRINTED COVERAGE BY AREA
SCALE: 20X

4226135/A 08/2020

NOTES: (continued)

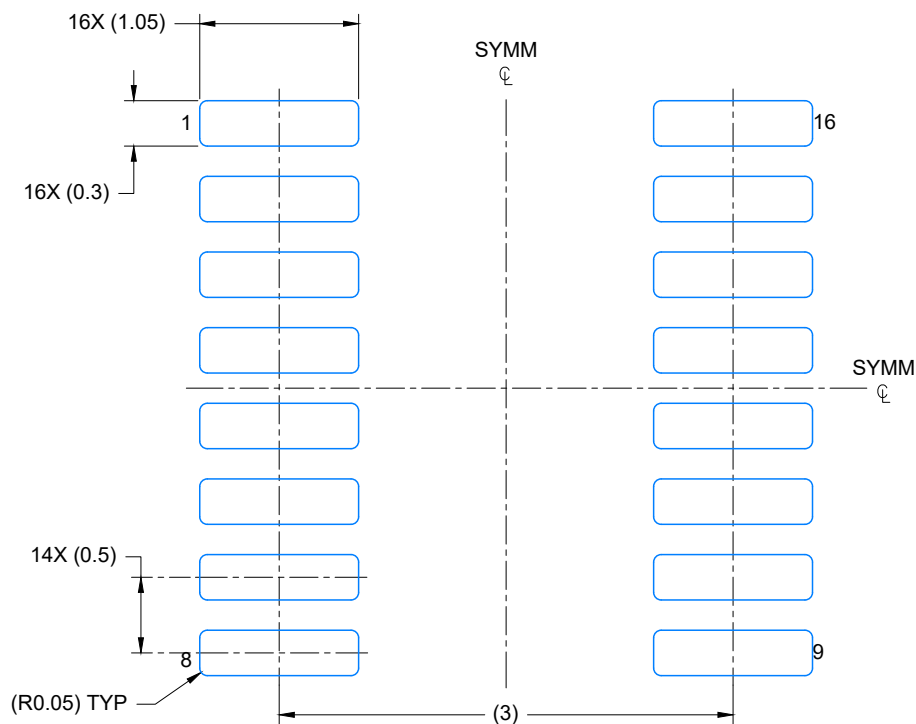
6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



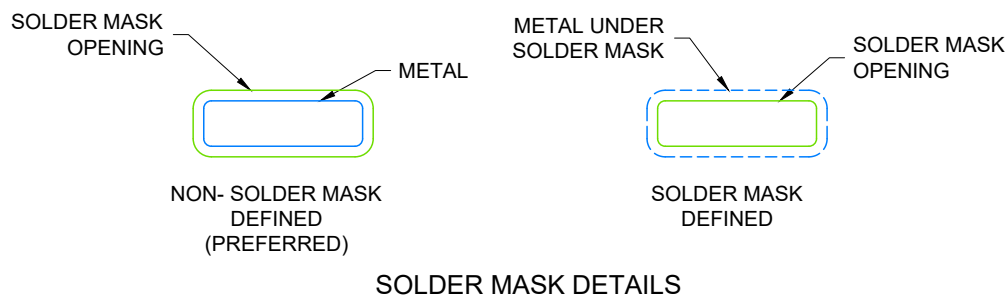
4224642/D 07/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
5. Reference JEDEC Registration MO-345, Variation AA



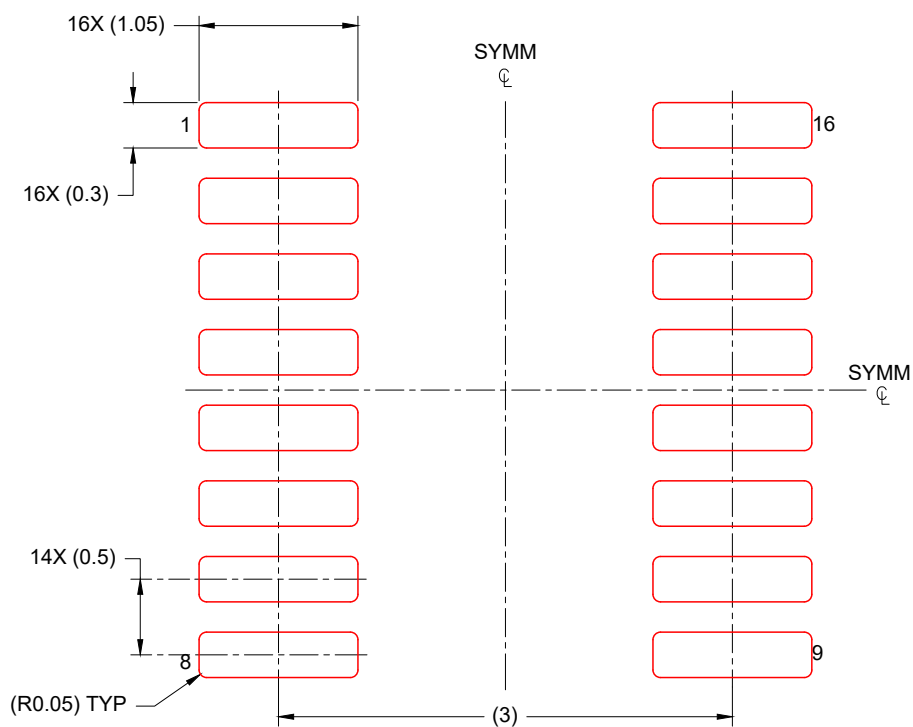
LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 20X



4224642/D 07/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 20X

4224642/D 07/2024

NOTES: (continued)

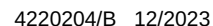
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.



PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



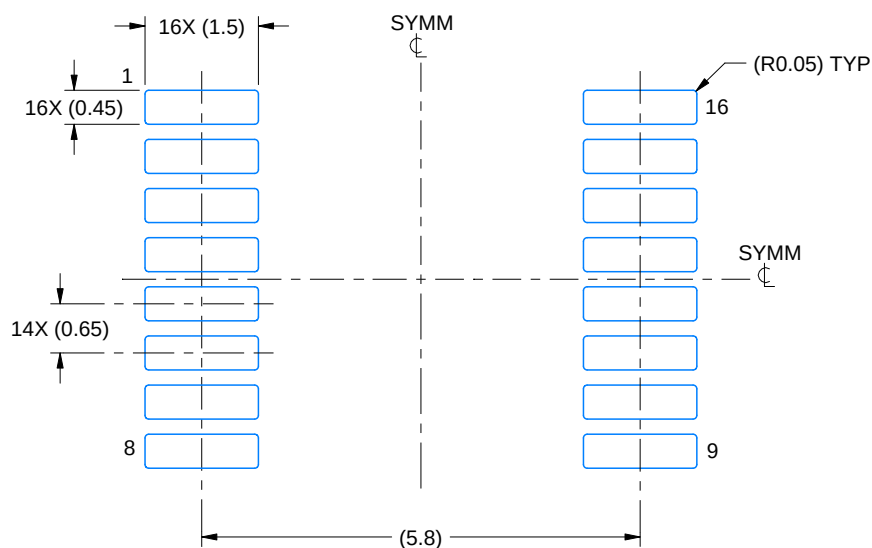
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

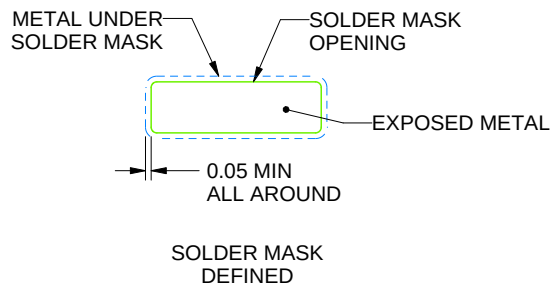
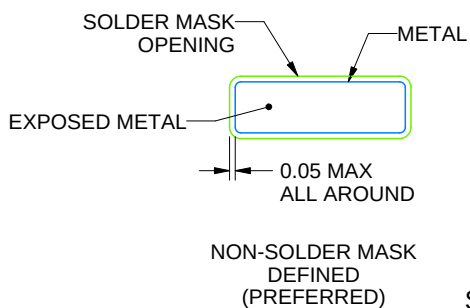
PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



SOLDER MASK DETAILS

4220204/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

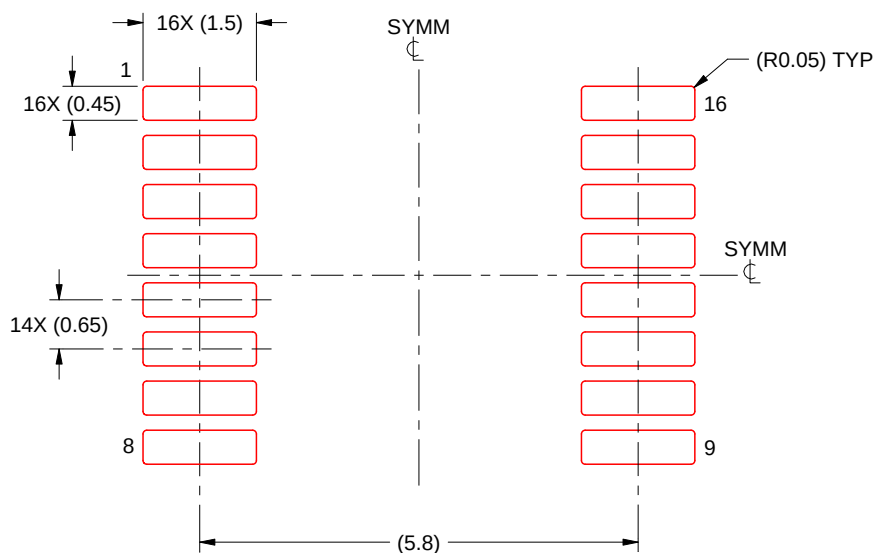
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220204/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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